



SI2333

Features

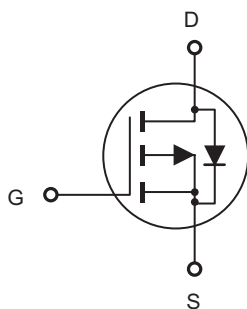
- Halogen free available upon request by adding suffix "-HF"
- TrenchFET Power Mosfet
- Excellent $R_{DS(ON)}$
- Marking Code: S33
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1

Maximum Ratings @ 25 °C Unless Otherwise Specified

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-source Voltage	-12	V
I_D	Drain Current-Continuous ⁽¹⁾	-6	A
I_{DM}	Drain Current-Pulsed	-20	A
V_{GS}	Gate-source Voltage	± 8	V
P_D	Total Power Dissipation	0.35 ⁽²⁾	W
		1.1 ⁽¹⁾	W
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	357 ⁽²⁾	°C/W
		113 ⁽¹⁾	°C/W
T_J	Operating Junction Temperature	-55 to +150	°C
T_{STG}	Storage Temperature	-55 to +150	°C

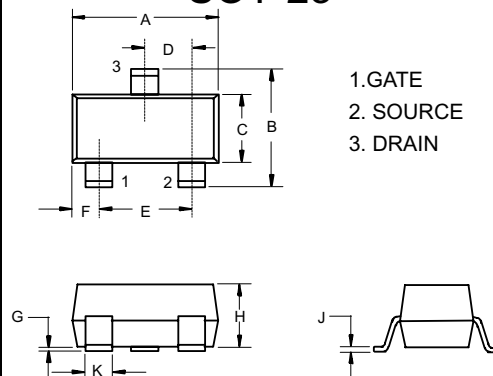
NOTE 1. Device mounted on FR-4 substrate board, with minimum recommended pad layout, single side.
2. Device mounted on no heat sink.

Internal Block Diagram



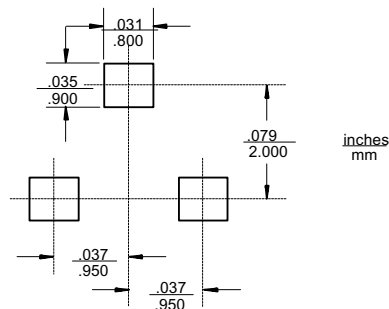
P-Channel Enhancement Mode Field Effect Transistor

SOT-23



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.110	.120	2.80	3.04	
B	.083	.104	2.10	2.64	
C	.047	.055	1.20	1.40	
D	.035	.041	.89	1.03	
E	.070	.081	1.78	2.05	
F	.018	.024	.45	.60	
G	.0005	.0039	.013	.100	
H	.035	.044	.89	1.12	
J	.003	.007	.085	.180	
K	.015	.020	.37	.51	

Suggested Solder Pad Layout



SI2333

Electrical characteristics (T_a=25°C unless otherwise noted)

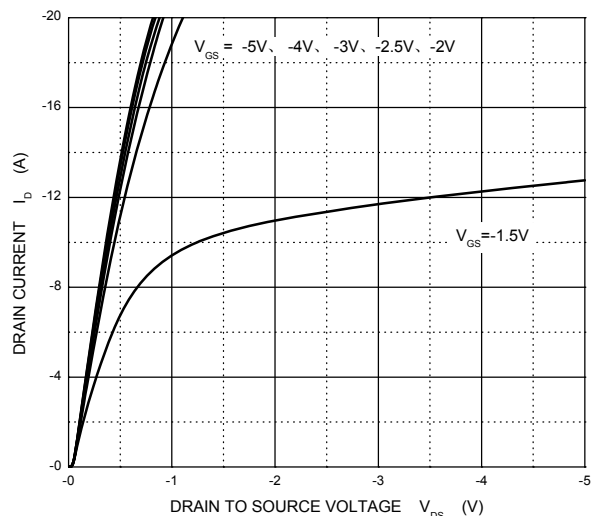
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	-12			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-12V,V _{GS} = 0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{GS} =±8V, V _{DS} = 0V			±0.1	
Gate threshold voltage (note 3)	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.4		-1	V
Drain-source on-resistance (note 4)	R _{DS(on)}	V _{GS} =-4.5V, I _D =-5A			28	mΩ
		V _{GS} =-3.7V, I _D =-4.6A			32	
		V _{GS} =-2.5V, I _D =-4.3A			40	
		V _{GS} =-1.8V, I _D =-1A			63	
		V _{GS} =-1.5V, I _D =-0.5A			150	
Forward tranconductance (note 3)	g _{FS}	V _{DS} =-5V, I _D =-5A		18		S
Dynamic characteristics (note 4)						
Input Capacitance	C _{iSS}	V _{DS} =-6V,V _{GS} =0V,f =1MHz		1275		pF
Output Capacitance	C _{oSS}			255		pF
Reverse Transfer Capacitance	C _{rSS}			236		pF
Gate resistance	R _g	f =1MHz	1.9		19	Ω
Total Gate Charge	Q _g	V _{DS} =-6V,V _{GS} =-4.5V,I _D =-5A		14	21	nC
Gate-Source Charge	Q _{gs}			2.3		nC
Gate-Drain Charge	Q _{gd}			3.6		nC
Turn-on delay time	t _{d(on)}	V _{DD} =-6V,V _{GEN} =-4.5V,I _D =-4A R _L =6Ω,R _{GEN} =1Ω		26	40	ns
Turn-on rise time	t _r			24	40	ns
Turn-off delay time	t _{d(off)}			45	70	ns
Turn-off fall time	t _f			20	35	ns
Source-Drain Diode characteristics						
Diode forward current	I _S	T _C =25°C			-1.4	A
Diode pulsed forward current	I _{SM}				-20	A
Diode Forward voltage (note 3)	V _{DS}	V _{GS} =0V, I _S =-4A			-1.2	V
Diode reverse recovery time (note 4)	t _{rr}	I _F =-4A,dI/dt=100A/μs		24	48	ns
Diode reverse recovery charge (note 4)	Q _{rr}			8	16	nC

Notes : 3. Pulse test; pulse width ≤ 300μs, duty cycles ≤ 2%.

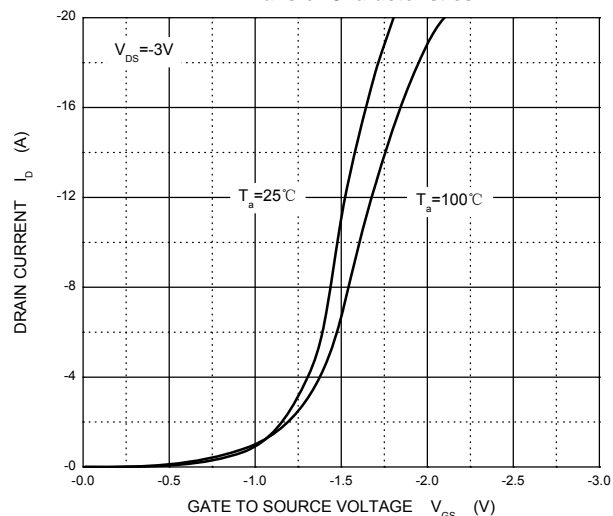
4. Guaranteed by design, not subject to production testing.

Typical Characteristics

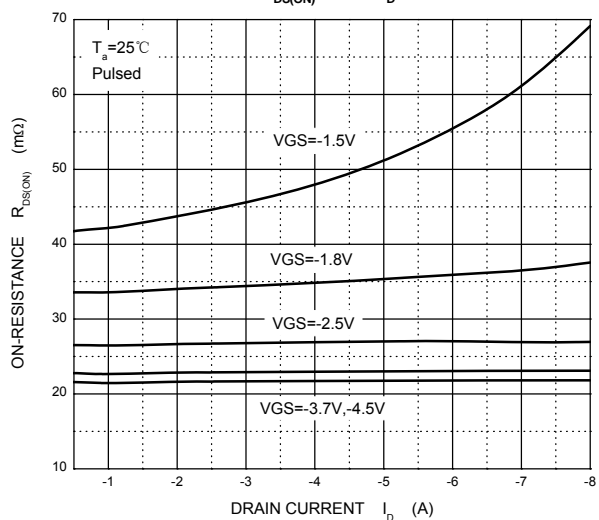
Output Characteristics



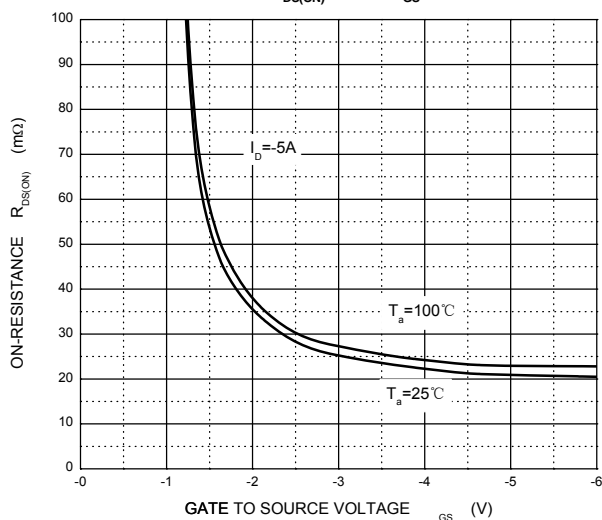
Transfer Characteristics



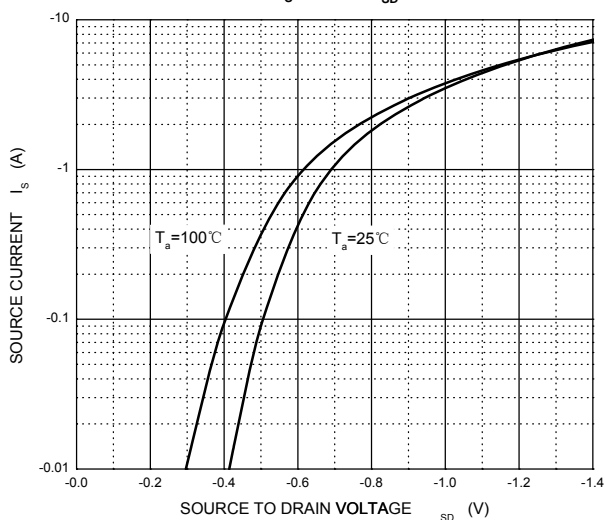
$R_{DS(ON)}$ — I_D



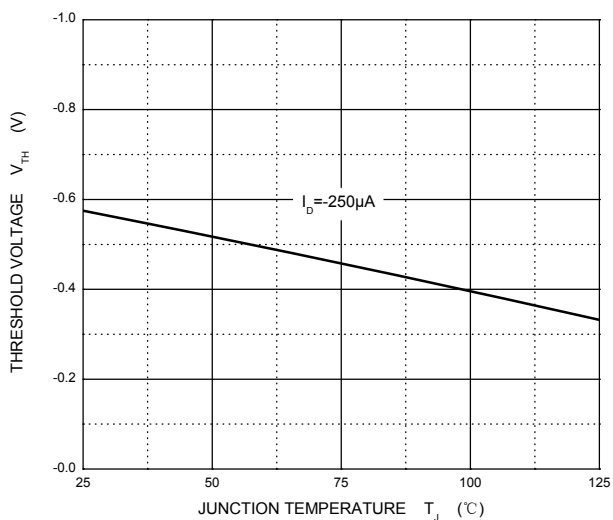
$R_{DS(ON)}$ — V_{GS}



I_S — V_{SD}



Threshold Voltage





Ordering Information :

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

IMPORTANT NOTICE

Micro Commercial Components Corp. reserves the right to make changes without further notice to any product herein to make corrections, modifications , enhancements , improvements , or other changes . **Micro Commercial Components Corp .** does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights ,nor the rights of others . The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp .** and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

CUSTOMER AWARENESS

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. **MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources.** MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.